List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Crystallization of CST225 thin film induced by a single femtosecond laser pulse: Experimental and theoretical study. Materials Science in Semiconductor Processing, 2022, 139, 106350.	1.9	10
2	Periodic Relief Fabrication and Reversible Phase Transitions in Amorphous Ge2Sb2Te5 Thin Films upon Multi-Pulse Femtosecond Irradiation. Micro, 2022, 2, 88-99.	0.9	8
3	Chalcogenide Thin Films—Holographic Media for Augmented Reality Devices. Applied Sciences (Switzerland), 2022, 12, 1934.	1.3	Ο
4	Low power reconfigurable multilevel nanophotonic devices based on Sn-doped Ge2Sb2Te5 thin films. Acta Materialia, 2022, 234, 117994.	3.8	11
5	Artificial Anisotropy in Ge2Sb2Te5 Thin Films after Femtosecond Laser Irradiation. Materials, 2022, 15, 3499.	1.3	6
6	Direct single-pass writing of two-phase binary diffraction gratings in a Ge2Sb2Te5 thin film by femtosecond laser pulses. Optics and Laser Technology, 2022, 153, 108212.	2.2	5
7	Experimental observation of two-stage crystallization of Ge2Sb2Te5 amorphous thin films under the influence of a pulsed laser. Journal of Alloys and Compounds, 2021, 851, 156924.	2.8	12
8	Chemical Modification of Phase Change Memory Materials Based on Complex Chalcogenides. Russian Journal of Inorganic Chemistry, 2021, 66, 281-287.	0.3	3
9	Thermal Stability of the Structure and Optical Properties of Nanostructured TIO2 Films. Russian Physics Journal, 2021, 63, 2045-2051.	0.2	2
10	Pyrimidine-Based Push–Pull Systems with a New Anchoring Amide Group for Dye-Sensitized Solar Cells. Electronic Materials, 2021, 2, 142-153.	0.9	12
11	Temperature activated conductivity of Ge ₂ Sb ₂ Te ₅ : connection to the variation of Fermi level and implications on resistance drift. Journal Physics D: Applied Physics, 2021, 54, 315302.	1.3	6
12	Rewritable and Tunable Laser-Induced Optical Gratings in Phase-Change Material Films. ACS Applied Materials & Interfaces, 2021, 13, 32031-32036.	4.0	16
13	Probing calorimetric heat transfer phenomena in multi-nanophase substances: A case study of some over-stoichiometric nanoarsenicals. Thermochimica Acta, 2021, 701, 178955.	1.2	Ο
14	Laser induced tunable Ge2Sb2Te5 phase-change gratings. Journal of Physics: Conference Series, 2021, 2015, 012154.	0.3	0
15	Size effect of the Ge2Sb2Te5 cell atop the silicon nitride O-ring resonator on the attenuation coefficient. APL Materials, 2021, 9, .	2.2	7
16	Tunable laser induced periodic surface structures in Ge2Sb2Te5 thin films. Journal of Physics: Conference Series, 2021, 2086, 012170.	0.3	0
17	Specific Features of Formation of Laserâ€Induced Periodic Surface Structures on Ge ₂ Sb ₂ Te ₅ Amorphous Thin Films under Illumination by Femtosecond Laser Pulses. Physica Status Solidi (B): Basic Research, 2020, 257, 1900617.	0.7	13
18	Investigation of Electrophysical Properties of ITO Films. Russian Physics Journal, 2020, 63, 1139-1143.	0.2	1

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19	Polydimethylsiloxane Elastomers Filled with Rod-Like α-MnO2 Nanoparticles: An Interplay of Structure and Electrorheological Performance. Polymers, 2020, 12, 2810.	2.0	1
20	Milling-driven nanonization of As S100- alloys from second glass-forming region: The case of lower-crystalline arsenicals (56 <x<66). 120339.<="" 2020,="" 549,="" journal="" non-crystalline="" of="" solids,="" td=""><td>1.5</td><td>4</td></x<66).>	1.5	4
21	Cyclometalated Ru(<scp>ii</scp>) complexes with tunable redox and optical properties for dye-sensitized solar cells. Dalton Transactions, 2020, 49, 16935-16945.	1.6	12
22	Kinetics of volume and surface driven crystallization in thin films. Journal of Physics Condensed Matter, 2020, 32, 355401.	0.7	3
23	Milling-driven nanonization of As S100- alloys from second glass-forming region: The case of higher-crystalline arsenicals (51 <x<56). 120086.<="" 2020,="" 539,="" journal="" non-crystalline="" of="" solids,="" td=""><td>1.5</td><td>4</td></x<56).>	1.5	4
24	Peculiarities of Estimating the Optical Band Gap of Thin Films of Phase Change Memory Materials. Inorganic Materials: Applied Research, 2020, 11, 330-337.	0.1	7
25	Direct observation of amorphous to crystalline phase transitions in Ge–Sb–Te thin films by grazing incidence X-ray diffraction method. Journal of Materials Science: Materials in Electronics, 2020, 31, 10196-10206.	1.1	4
26	Influence of the Degree of Crystallinity on the Dispersion of the Optical Parameters of Ge2Sb2Te5 Phase-Change Memory Thin Films. Semiconductors, 2020, 54, 1775-1783.	0.2	4
27	Molecular Complex of Cadmium(II) Trifluoroacetate with Triphenylphosphine: Crystal Structure and Luminescence Properties. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2019, 45, 473-477.	0.3	0
28	Synthesis and photovoltaic properties of new thieno[3,2-b]indole-based dyes. Russian Chemical Bulletin, 2019, 68, 1208-1212.	0.4	7
29	Surfactant-Switched Positive/Negative Electrorheological Effect in Tungsten Oxide Suspensions. Molecules, 2019, 24, 3348.	1.7	6
30	CsPbI3 Perovskite Nanoparticles: Room-Temperature Synthesis and Optical Study. Russian Journal of Inorganic Chemistry, 2019, 64, 1587-1591.	0.3	3
31	The vacuum arc ion source for indium and tin ions implantation into phase change memory thin films. Review of Scientific Instruments, 2019, 90, 123313.	0.6	2
32	Laser-induced modification and formation of periodic surface structures (ripples) of amorphous GST225 phase change materials. Optics and Laser Technology, 2019, 113, 87-94.	2.2	18
33	Laser-induced modification of amorphous GST225 phase change materials. Materiaux Et Techniques, 2019, 107, 307.	0.3	2
34	Black hybrid iodobismuthate containing linear anionic chains. New Journal of Chemistry, 2018, 42, 6354-6363.	1.4	30
35	Isothermal and CW laser crystallization of amorphous Ge2Sb2Te5 thin films. Journal of Non-Crystalline Solids, 2018, 480, 51-56.	1.5	4
36	Synthesis, crystal structure and optical properties of 1,1'-(1,n-alkanediyl)bis(3-methylimidazolium) halobismuthates. Journal of Molecular Structure, 2018, 1151, 186-190.	1.8	6

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37	Multiple thermal cycling and phase transitions in Ge-Sb-Te materials. Journal of Non-Crystalline Solids, 2018, 501, 101-105.	1.5	1
38	Coordination Polymeric Ensemble of Silver with Nitrate and 4-(Aminomethyl)benzoate: Synthesis, Crystal Structure, and Luminescence Properties. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2018, 44, 722-727.	0.3	0
39	Characteristics of Amorphous As2S3 Semiconductor Films Obtained via Spin Coating. Semiconductors, 2018, 52, 1963-1968.	0.2	1
40	Laser-Induced Modification of the Surface of Ge2Sb2Te5 Thin Films: Phase Changes and Periodic-Structure Formation. Semiconductors, 2018, 52, 809-815.	0.2	9
41	Coordination Compounds of Silver Methanesulfonate with Triphenylphosphine and 1,2-Bis(4-Pyridyl)ethane. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2018, 44, 103-108.	0.3	1
42	Cadmium Iodide Complex with 4-Aminomethylbenzoic Acid: Synthesis, Crystal Structure, and Luminescent Properties. Russian Journal of Inorganic Chemistry, 2018, 63, 333-337.	0.3	2
43	The Influence of Materials of Electrodes of Sensitized Solar Cells on Their Capacitive and Electrical Characteristics. Russian Physics Journal, 2018, 61, 196-202.	0.2	3
44	Dielectric Properties of Nanocrystalline Tungsten Oxide in the Temperature Range of 223–293 K. Semiconductors, 2018, 52, 885-890.	0.2	5
45	Effect of doping on the crystallization kinetics of phase change memory materials on the basis of Ge–Sb–Te system. Journal of Thermal Analysis and Calorimetry, 2017, 127, 283-290.	2.0	15
46	The design and synthesis of thiophene-based ruthenium(II) complexes as promising sensitizers for dye-sensitized solar cells. Dyes and Pigments, 2017, 140, 169-178.	2.0	15
47	Electrophysical Properties of Ge–Sb–Te Thin Films for Phase Change Memory Devices. Russian Physics Journal, 2017, 59, 1417-1424.	0.2	2
48	Integral isoconversional method for evaluating crystallization parameters of thin films of Ge2Sb2Te5 phase change memory materials. Inorganic Materials, 2017, 53, 45-49.	0.2	1
49	Electrical properties and transport mechanisms in phase change memory thin films of quasi-binary-line GeTe–Sb2Te3 chalcogenide semiconductors. Semiconductors, 2017, 51, 146-152.	0.2	2
50	The dielectric properties and flow of electrorheological fluids based on polymer-coated nanodispersed barium tetraacetate titanyl particles upon a dynamic shear in electric fields. Colloid Journal, 2017, 79, 204-211.	0.5	8
51	Synthesis, thermal stability, crystal structure and optical properties of 1,1′-(1, n) Tj ETQq1 1 0.784314 rgBT	/Overlock :	10 Tf 50 182
52	Temperature and spectral dependence of CH3NH3PbI3 films photoconductivity. Applied Physics Letters, 2017, 110, .	1.5	15
53	Novel push-pull thieno[2,3-b]indole-based dyes for efficient dye-sensitized solar cells (DSSCs). Arkivoc, 2017, 2017, 34-50.	0.3	7
54	Bis(4-cyano-1-pyridino)pentane halobismuthates. Light-harvesting material with an optical band gap of 1.59 eV. Mendeleev Communications, 2017, 27, 271-273.	0.6	27

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55	Isothermal crystallization of Ge ₂ Sb ₂ Te ₅ amorphous thin films and estimation of information reliability of PCM cells. Physica Status Solidi (A) Applications and Materials Science, 2016, 213, 1831-1838.	0.8	13
56	Bimetallic 3d—4f-molecules [MEu(ButCOO)5(1,10-phen)] (M = Zn2+, Co2+, phen is phenanthroline): synthesis, structure, luminescent and magnetic properties. Russian Chemical Bulletin, 2016, 65, 1488-1494.	0.4	9
57	Chemical surface treatment of Ge ₂ Sb ₂ Te ₅ thin films for phase change memory application. Proceedings of SPIE, 2016, , .	0.8	0
58	Electrical properties of the Ge2Sb2Te5 thin films for phase change memory application. AIP Conference Proceedings, 2016, , .	0.3	12
59	Synthesis, crystal structure, and luminescent properties of silver complexes with 2-methylquinoline. Russian Journal of Inorganic Chemistry, 2016, 61, 1538-1544.	0.3	1
60	Influence of Ti Doping on the Properties of Ge-Sb-Te Thin Films for Phase Change Memory. Solid State Phenomena, 2016, 247, 30-38.	0.3	1
61	A hybrid halobismuthate light-harvesting material with an optical band gap of 1.70 eV. New Journal of Chemistry, 2016, 40, 10041-10047.	1.4	22
62	Reactions of 2,2′-Pyridyl with the cadmium(II) compounds: Synthesis, crystal structure, and luminescence properties of [Cd(Pic)2(H2O)2] · H2O. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2016, 42, 614-619.	0.3	1
63	Voltage oscillations in the case of the switching effect in thin layers of Ge–Sb–Te chalcogenides in the current mode. Semiconductors, 2016, 50, 941-946.	0.2	1
64	Using extraction and sorption processes to obtain nanosized powders of calcium silicates and functional materials on their basis. Theoretical Foundations of Chemical Engineering, 2016, 50, 490-497.	0.2	3
65	Four- and five-coordinate metal atoms in a supramolecular polymeric assembly of silver(I) with (4-methyl-2-quinolylthio)acetate. Russian Journal of Inorganic Chemistry, 2016, 61, 1397-1402.	0.3	0
66	Tetranuclear Heterometallic {Zn ₂ Eu ₂ } Complexes With 1â€Naphthoate Anions: Synthesis, Structure and Photoluminescence Properties. Chemistry - an Asian Journal, 2016, 11, 604-612.	1.7	30
67	Synthesis, crystal structure, and luminescent properties of a new modification of the zinc(II) dichloride complex with phthalazine. Russian Journal of Inorganic Chemistry, 2016, 61, 583-587.	0.3	2
68	Coordination silver polymer with the bridging anion of oxadiazolylacrylic acid: Synthesis, crystal structure, and luminescence properties. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2016, 42, 361-366.	0.3	6
69	Iridium(III) 2â€Phenylbenzimidazole Complexes: Synthesis, Structure, Optical Properties, and Applications in Dyeâ€5ensitized Solar Cells. European Journal of Inorganic Chemistry, 2016, 2016, 347-354.	1.0	36
70	Destructive Clustering of Metal Nanoparticles in Chalcogenide and Oxide Glassy Matrices. Nanoscale Research Letters, 2016, 11, 34.	3.1	5
71	Influence of indium doping on the electrical properties of Ge ₂ Sb ₂ Te ₅ thin films for nonvolatile phase change memory devices. Journal of Physics: Conference Series, 2016, 690, 012006.	0.3	11
72	Investigation of the Crystallization Kinetics in Ge-Sb-Te-Bi Thin Films for Phase Change Memory Application. Acta Physica Polonica A, 2016, 129, 717-720.	0.2	1

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73	Influence of the Composition on the Thermoelectric and Electro-physical Properties of Ge-Sb-Te Thin Films for Phase Change Memory Application. Journal of Nano- and Electronic Physics, 2016, 8, 03033-1-03033-4.	0.2	1
74	One Step Microwave-Assisted Synthesis of Fluorinated Titania Photocatalyst. Key Engineering Materials, 2015, 670, 177-182.	0.4	1
75	Coordination polymer of silver(I) perrhenate with quinoxaline: Synthesis, crystal structure, and luminescence properties. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2015, 41, 747-750.	0.3	4
76	Electrical properties and transport mechanisms in Ge-Sb-Te thin films for nanoelectronics. , 2015, , .		1
77	Oxygen incorporation into GST phase-change memory matrix. Applied Surface Science, 2015, 332, 533-541.	3.1	47
78	Synthesis, crystal structure, and luminescence properties of the complex of silver(I) perrhenate with N-(2-aminoethyl)piperazine. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2015, 41, 362-367.	0.3	1
79	Supramolecular assemblies based on 1,5-naphthalene disulfonic acid: Synthesis, crystal structure, and luminescent properties. Russian Journal of Inorganic Chemistry, 2015, 60, 151-156.	0.3	2
80	Positronics of radiation-induced effects in chalcogenide glassy semiconductors. Semiconductors, 2015, 49, 298-304.	0.2	3
81	Synthesis, Photophysical and Redox Properties of the D–Ĩ€â€"A Type Pyrimidine Dyes Bearing the 9-Phenyl-9H-Carbazole Moiety. Journal of Fluorescence, 2015, 25, 763-775.	1.3	31
82	Intrinsic phase separation in low-temperature quenched arsenic trisulfide glass. Journal of Non-Crystalline Solids, 2015, 430, 16-20.	1.5	8
83	Luminophores based on synthetic calcium silicates. Theoretical Foundations of Chemical Engineering, 2015, 49, 706-713.	0.2	3
84	A facile and convenient synthesis and photovoltaic characterization of novel thieno[2,3-b]indole dyes for dye-sensitized solar cells. Synthetic Metals, 2015, 199, 152-158.	2.1	35
85	Binuclear complex of silver(I) perrhenate with phthalazine: Synthesis, crystal structure, and luminescence properties. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2014, 40, 871-874.	0.3	2
86	A complex of cadmium(II) iodide with 4-cyanopyridine: Synthesis, crystal structure, and luminescent properties. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2014, 40, 801-805.	0.3	4
87	Influence of doping on the crystallization kinetics of Ge-Sb-Te thin films for phase-change memory application. Proceedings of SPIE, 2014, , .	0.8	0
88	Investigation of transport mechanisms in Bi doped Ge ₂ Sb ₂ Te ₅ thin films for phase change memory application. Proceedings of SPIE, 2014, , .	0.8	7
89	Peculiarities of Bi doping of Ge–Sb–Te thin films for PCM devices. Canadian Journal of Physics, 2014, 92, 684-689.	0.4	20
90	Synthesis and photoelectrochemical properties of cyclometallated ruthenium(II) complex. Russian Journal of Inorganic Chemistry, 2014, 59, 658-664.	0.3	1

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91	Cadmium(II) iodide molecular coordination compounds with 4-methylpyridine and 4-methylquinoline. Russian Journal of Inorganic Chemistry, 2014, 59, 738-742.	0.3	1
92	Coordination disordering in near-stoichiometric arsenic sulfide glass. Journal of Non-Crystalline Solids, 2014, 402, 236-243.	1.5	20
93	Estimation of kinetic parameters for the phase change memory materials by DSC measurements. Journal of Thermal Analysis and Calorimetry, 2014, 117, 1509-1516.	2.0	21
94	Cyclometalated ruthenium complex as a promising sensitizer in dye-sensitized solar cells. Russian Journal of Electrochemistry, 2014, 50, 503-509.	0.3	12
95	Influence of bismuth on the optical properties of Ge2Sb2Te5 thin films. Semiconductors, 2014, 48, 577-583.	0.2	6
96	Current-voltage characteristics of thin Ge2Sb2Te5 films taken using a measuring circuit with a current source. Technical Physics, 2014, 59, 546-550.	0.2	9
97	Coordination molecular compounds of cadmium(II) iodide with dimethylpyridines. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2014, 40, 366-370.	0.3	7
98	Free volume fragmentation in glassy chalcogenides during natural physical ageing as probed by PAL spectroscopy. Journal of Non-Crystalline Solids, 2013, 377, 49-53.	1.5	20
99	Information reliability evaluation of a Ge2Sb2Te5-based phase change memory cell. Inorganic Materials, 2013, 49, 878-882.	0.2	2
100	Synthesis, crystal structure, and luminescent properties of a silver(I) perrhenate complex with phenazine. Russian Journal of Inorganic Chemistry, 2013, 58, 523-526.	0.3	0
101	Structural Changes in Doped Ge2Sb2Te5 Thin Films Studied by Raman Spectroscopy. Physics Procedia, 2013, 44, 82-90.	1.2	39
102	Coordination compounds of cobalt(II) and cadmium(II) with 2-amino-4-methylpyrimidine: Synthesis, crystal structure, and luminescent properties. Russian Journal of Inorganic Chemistry, 2013, 58, 1187-1192.	0.3	5
103	Phase separation in chalcogenide semiconductors of the Ge-Te system upon thermal cycling. Semiconductors, 2013, 47, 1680-1683.	0.2	0
104	Silver complexes with 2-amino-4-methylpyrimidine: Synthesis, crystal structure, and luminescent properties. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2013, 39, 565-570.	0.3	5
105	Iron complex redox system as a mediator for a dye-sensitized solar cell. Russian Journal of Inorganic Chemistry, 2013, 58, 62-66.	0.3	2
106	Thermal properties of phase change material Ge2Sb2Te5 doped with Bi. Journal of Non-Crystalline Solids, 2013, 377, 26-29.	1.5	17
107	Photoelectrochemical cells based on nanocrystalline TiO2 synthesized by high temperature hydrolysis of ammonium dihydroxodilactatotitanate(IV). Russian Journal of Electrochemistry, 2013, 49, 423-427.	0.3	1
108	Synthesis, crystal structures, and luminescence spectra of the coordination compounds of cadmium(II) iodide with hexamethylenetetramine. Russian Journal of Coordination Chemistry/Koordinatsionnaya Khimiya, 2012, 38, 657-661.	0.3	1

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109	Synthesis, structure, thermal behavior, thermodynamic, magnetic and luminescent properties of Pr, Sm, Eu, and Gd cymantrenecarboxylates. Polyhedron, 2012, 43, 36-46.	1.0	24
110	Synthesis, crystal structure, and luminescence properties of the tetranuclear complex of cadmium(II) acetate with 4,4′-(1,4-phenylenediisopropylidene)bis-aniline. Russian Journal of Inorganic Chemistry, 2012, 57, 1553-1558.	0.3	1
111	Switching and memory effects in partly crystallized amorphous Ge2Sb2Te5 films in a current controlled mode. Journal of Non-Crystalline Solids, 2012, 358, 3299-3303.	1.5	17
112	Novel oxovanadium(iv) heterochelate complexes: synthesis, structure, ESR spectra, and photoluminescence properties. Russian Chemical Bulletin, 2012, 61, 1084-1092.	0.4	6
113	Relaxation processes in glassy selenium. Inorganic Materials, 2012, 48, 309-312.	0.2	4
114	Phase transitions in thin Ge2Sb2Te5 chalcogenide films according to Raman spectroscopy data. Semiconductors, 2012, 46, 591-594.	0.2	4
115	Short-range order evolution in S-rich Ge–S glasses by X-ray photoelectron spectroscopy. Journal of Non-Crystalline Solids, 2011, 357, 1797-1803.	1.5	18
116	Erbium photoluminescence in potential ErQ3 phosphor for organic LEDs. Technical Physics Letters, 2011, 37, 714-717.	0.2	0
117	Switching effects in the films based on Ge2Sb2Te5. Journal of Communications Technology and Electronics, 2011, 56, 188-191.	0.2	0
118	Phase-change-memory materials based on system chalcogenides and their application in phase-change random-access memory. Nanotechnologies in Russia, 2011, 6, 227-236.	0.7	12
119	Valence band structure of binary chalcogenide vitreous semiconductors by high-resolution XPS. Semiconductors, 2011, 45, 423-426.	0.2	7
120	Binuclear zinc naphthoate complex with 1,10-phenanthroline: synthesis, structure, and photoluminescence properties. Russian Chemical Bulletin, 2011, 60, 1012-1015.	0.4	6
121	Influence of doping on the structure and optical characteristics of Ge2Sb2Te5amorphous films. Physica Status Solidi C: Current Topics in Solid State Physics, 2011, 8, 2688-2691.	0.8	14
122	Synthesis, structure and redox properties of new cobalt(II) and nickel(II) complexes with 6-ferrocenyl-2,2′-bipyridyl. Journal of Organometallic Chemistry, 2011, 696, 2607-2610.	0.8	9
123	Influence of chalcogenide glasses electro physical parameters on threshold voltage for phase-change memory. Thin Solid Films, 2010, 518, 5656-5658.	0.8	8
124	Synthesis and characterization of As ₂ X ₃ (X = Se, S)–Eu (THD) ₃ hybrid materials. Physica Status Solidi C: Current Topics in Solid State Physics, 2010, 7, 881-884.	0.8	0
125	Conductivity oscillations in Ge2Sb2Te5films stimulated by phase transformations. Physica Status Solidi C: Current Topics in Solid State Physics, 2010, 7, NA-NA.	0.8	1
126	Thermal effects in Ge-Sb-Te phase- change memory materials during multiple thermal cycling. Physica Status Solidi C: Current Topics in Solid State Physics, 2010, 7, NA-NA.	0.8	14

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127	Cluster modeling of quasiâ€adaptive phases in vitreous germanium selenides. Physica Status Solidi C: Current Topics in Solid State Physics, 2010, 7, 921-924.	0.8	5
128	Physical aging of chalcogenide glasses. Inorganic Materials, 2010, 46, 911-913.	0.2	21
129	High-energy γ-irradiation effect on physical ageing in Ge–Se glasses. Nuclear Instruments & Methods in Physics Research B, 2009, 267, 2958-2961.	0.6	17
130	Long-term ageing behaviour in Ge–Se glasses. Journal of Materials Science, 2009, 44, 3962-3967.	1.7	29
131	Structural transformations in thin Ge2Sb2Te5 films. Inorganic Materials, 2009, 45, 361-365.	0.2	3
132	Electrical conductivity of amorphous films of chalcogenide compounds in high electric fields. Semiconductors, 2009, 43, 921-924.	0.2	6
133	Structural paradigm of Se-rich Ge–Se glasses by high-resolution x-ray photoelectron spectroscopy. Journal of Applied Physics, 2009, 105, 103704.	1.1	42
134	Retrieval of some parameters of an amorphous chalcogenide semiconductor from the temperature and field dependences of its conductivity. Inorganic Materials, 2008, 44, 1190-1193.	0.2	0
135	Rutherford backscattering spectroscopy and surface morphology of amorphous As2Se3 films modified with complex compounds Ln(THD)3 (Ln=Eu, Tb, Er, Yb). Journal of Physics and Chemistry of Solids, 2007, 68, 1117-1120.	1.9	Ο
136	Molecular structure of As x Se100 â^' x glasses studied by x-ray spectroscopy. Inorganic Materials, 2007, 43, 897-900.	0.2	5
137	Photoluminescence and composition of amorphous As2Se3 films modified with Er(thd)3 complex compound. Semiconductors, 2007, 41, 914-920.	0.2	4
138	Amorphous arsenic chalcogenide films modified using rare-earth complexes. Journal of Non-Crystalline Solids, 2006, 352, 1547-1550.	1.5	3
139	Anomalous mechanical properties of tellurium-modified glassy selenium. Inorganic Materials, 2006, 42, 210-214.	0.2	5
140	Nuclear microanalysis of amorphous As2Se3 films modified with Ln(thd)3 (Ln = Eu, Tb). Inorganic Materials, 2006, 42, 850-854.	0.2	3
141	The properties of amorphous arsenic chalcogenide films modified by rare-earth complexes. Semiconductors, 2005, 39, 978-982.	0.2	1
142	Deformation of Glassy Selenium above Its Softening Temperature. Inorganic Materials, 2005, 41, 533-536.	0.2	1
143	Changes in the Short-Range Order of Chalcogenide Glasses upon Crystallization. Inorganic Materials, 2004, 40, 666-668.	0.2	2
144	Amorphous Arsenic Chalcogenide Films Modified Using Rare-Earth Complexes. Inorganic Materials, 2004, 40, 791-796.	0.2	6

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145	Determination of the parameters of photoinduced centers in glassy GeS2.2 from the noise spectrum of the optical electroabsorption signal. JETP Letters, 1997, 65, 883-888.	0.4	0
146	Dynamics of photostimulated structure metastability formation in vitreous GeS2.2 by optical electroabsorption. Solid State Communications, 1994, 90, 807-808.	0.9	1
147	Registration of structure metastability of vitreous GeS2 by optical electroabsorption. Solid State Communications, 1994, 89, 341-343.	0.9	4
148	The experimental observation and investigation of defects in glass forming substances with selenium as an example by viscosimetry in magnetic and electric fields. Materials Research Bulletin, 1982, 17, 801-807.	2.7	8
149	Investigation of defects in amorphous selenium by viscosimetry in electric fields. Resonance phenomenon and the impurities influence. Solid State Communications, 1982, 44, 1561-1564.	0.9	2
150	Hydrothermal Synthesis of Nanocrystalline Titanium Dioxide for Use as a Photoanode of DSSCs. Key Engineering Materials, 0, 670, 156-161.	0.4	1